

# A Study on Feed forward Technique In CMOS OTA Circuits

Manoj K. Taleja,

Department of Electronics & Communication Engg.,  
 Guru Jambheshwar University of Science &  
 Technology Hisar, Haryana, (India)

Manoj Kumar,

Department of Electronics & Communication Engg.,  
 Guru Jambheshwar University of Science &  
 Technology Hisar, Haryana, (India)

## ABSTRACT

In this paper, a study in terms of gain, unity gain frequency of operational transconductance amplifiers (OTAs) using feedforward technique with FDCM has been carried out. OTA having feedforward technique with FDCM shows gain of 68 dB at 1nA bias current and 10 KHz - 1GHz unity gain frequency characteristics. The input bias current from 1nA to 1mA has been varied for study. The CMOS OTA has been simulated in 0.5 $\mu$ m technology with 2.5V power supply voltage.

## 1. INTRODUCTION

In the recent years, with the scaling of modern CMOS technologies and wide use of portable equipments reduction of the supply voltage in integrated circuits has increased rapidly. Research efforts have been made in reducing total power consumption and improving the noise margin of the operational amplifiers. Implementation of very large scale integrated circuits (VLSI) systems with low supply voltages has become a challenging task in the design of modern analog and digital circuits. The realization of high-speed, high gain, large gain-bandwidth product, and low power amplifiers demands efficient circuit design techniques [1]. With reduction in channel length, cut-off frequency of the transistor increases and realization of CMOS wideband amplifiers becomes more feasible [2]. In the design of wideband amplifiers both in bipolar and CMOS technology, a folded cascode configuration has been widely used [3]. The reason is that the output capacitance plays the same role as the compensation capacitance in these configurations [4]. A current mirror has advantage of low-voltage operation for a wide range as compared to a folded cascode configuration [5]. Further folded cascode requires an additional VDSsat for the common gate transistor. For low voltage operations, this VDSsat reduces the output voltage range. A feedforward is a compensation technique in which a buffer is used to break the bidirectional path through the compensation capacitor [6]. The use of a current mirror with feedforward technique produces a lower nondominant pole than a folded cascode amplifier. Feedforward technique with FDCM is generally used to increase the unity gain frequency of the amplifiers. The cascode amplifier high has high output impedance and can accomplish very high voltage gain. It has characteristics to increase the gain without affecting the frequency but has the disadvantages of reducing the output voltage swing.

## 2. FEEDFORWARD TECHNIQUE

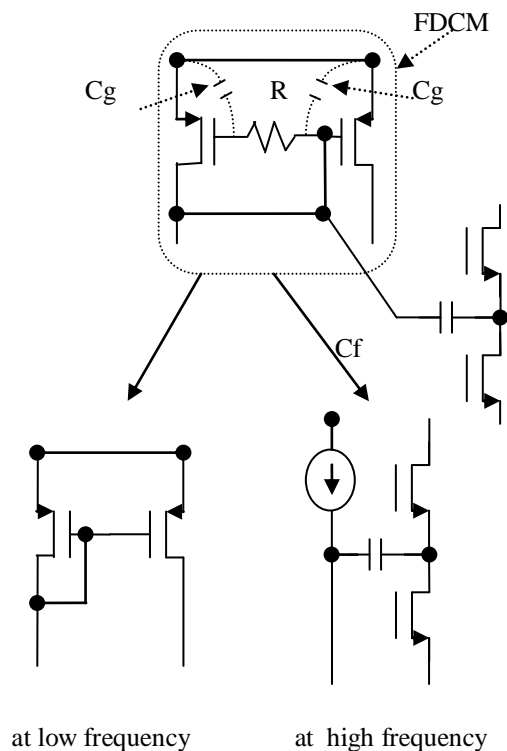
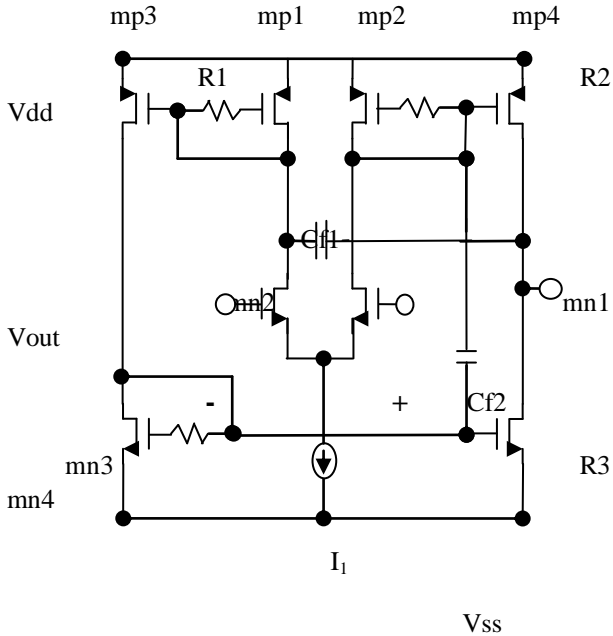


Figure 1: Operation of FDCM with feed forward capacitor

The feedforward technique is not much suitable for the conventional current mirror, because high-frequency (HF) component of an input signal flows through the transistor due to its low-input impedance. The input impedance of the current mirror should be large for high frequency signals while it should be small for low frequencies and DC operation. So a FDCM is required for effective feedforward. A resistor is connected between the drain and the gate of the transistor with gate-source capacitance to make a low pass filter. The operation of the feedforward technique with FDCM is shown in Figure 1. Since the low-frequency signals and DC signals pass through the LPF so the input impedance of the current mirror becomes low. For higher frequencies than the cut-off frequency of the LPF, it becomes higher. The input transistor of the current mirror plays the role of a current

source. So, the high-frequency signals flow through the feedforward capacitor  $C_f$ . To compensate for the loss of gate source capacitance  $C_g$ ,  $C_f$  is made approximately 10 times larger than  $C_g$ .



**Figure 2: Wideband amplifier with feed forward technique.**

For high frequency signals, large transistors are used.  $C_g$  is around 0.5 to 2.0 pF depending upon process technology. Using resistors of 100  $\Omega$  - 1 k $\Omega$  and without generating a noise, the HF signal of 10 KHz - 1 GHz successfully bypasses the FDCM. A wideband amplifier using feedforward technique with the FDCM is shown in Figure 2. The high frequency signals of the output current of mn2 are fed forward to the output node through  $C_{f1}$ . While the signal from mn1 is fed forward to the input of another FDCM through  $C_{f2}$  and is amplified. In the conventional amplifier, the channel length of the transistors should be short for shifting the poles to higher frequencies by sacrificing the gain. When the channel length is long and the gate-source capacitance is large, the technique with FDCM's is expected to show greater improvement.

The transconductance  $g_m$  of an OTA is proportional to the load capacitance,  $C_L$  and gain bandwidth product, GBW. It is given by:

$$g_m, I = GBW \cdot 2\pi C_L$$

To obtain a large gain bandwidth product (GBW), transistors with large transconductance are required. So, the bias currents should be large for the input transistors. The voltage gain of the amplifier is given by:

$$AV = AV1 \cdot AV2$$

Where  $AV1$  and  $AV2$  are given by:

$$AV1 = g_{m8} / g_{m2} = g_{m7} / g_{m6}$$

$$AV2 = \frac{1}{2} \cdot Z_0 (g_{m1} + g_{m3})$$

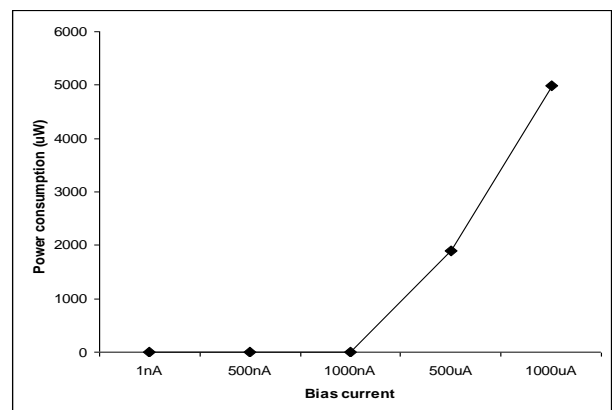
$$Z_0 = [r_{ds11} \cdot g_{m11} \cdot r_{ds1}] // [r_{ds12} \cdot g_{m12} \cdot r_{ds3}]$$

### 3. RESULTS

CMOS OTA using feedforward with FDCM technique is simulated using standard 0.5  $\mu\text{m}$  CMOS technology. The amplifier operate at 2.5 V power supply voltage with a bias current of 1 nA. All p-channel transistor's body terminals are connected to VDD and of n-channel transistors to VSS. The unity gain frequency of CMOS OTA using feedforward with FDCM technique is 10 KHz - 1 GHz. The gain of CMOS OTA using feedforward with FDCM technique is 68 dB at 1nA bias current. The results are shown in Table 1. Further the power consumption and bias current relation has been studied. It has been observed that power consumption increase with increased in bias current as shown in figure 3

**Table 1: Simulated performance characteristics for CMOS amplifiers**

Design parameters	OTA using feedforward with FDCM technique [5]	Conventional amplifier [7]
Power supply	2.5 V	2.5 V
DC voltage gain	68 dB	48 dB
Unity gain freq.	10 KHz-1GHz	1 KHz - 150 MHz
Input bias current	1 nA - 1 mA	1 mA



**Figure 3: Power consumption with bias current**

#### **4. CONCLUSION**

In this paper, a 0.5 $\mu$ m CMOS OTA using feedforward with frequency-dependent current mirror (FDCM) technique has been studied. This technique has been evaluated in terms of gain, unity gain frequency characteristics. The gain of 68 dB at 1 nA bias current and unity gain frequency of 10 KHz – 1 GHz has been calculated using feedforward with frequency-dependent current mirror (FDCM) technique. Power consumption of circuit shows increasing trend with increasing in bias current.

#### **5. REFERENCES**

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